

## **General Purpose Transistors**

#### **NPN Silicon**

# MMBT2222L, MMBT2222AL, SMMBT2222AL

#### **Features**

- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable

#### **MAXIMUM RATINGS**

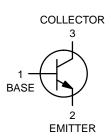
| Rating  | Symbol           | Value      | Unit |
|---|------------------|------------|------|
| Collector-Emitter Voltage  MMBT2222L  MMBT2222AL, SMMBT2222AL | V <sub>CEO</sub> | 30<br>40   | Vdc  |
| Collector-Base Voltage  MMBT2222L  MMBT2222AL, SMMBT2222AL    | V <sub>CBO</sub> | 60<br>75   | Vdc  |
| Emitter-Base Voltage  MMBT2222L  MMBT2222AL, SMMBT2222AL      | V <sub>EBO</sub> | 5.0<br>6.0 | Vdc  |
| Collector Current – Continuous                                | Ic               | 600        | mAdc |
| Collector Current – Peak (Note 3)                             | I <sub>CM</sub>  | 1100       | mAdc |

#### THERMAL CHARACTERISTICS

| Characteristic  | Symbol                            | Max         | Unit        |
|---|-----------------------------------|-------------|-------------|
| Total Device Dissipation FR-5 Board<br>(Note 1) T <sub>A</sub> = 25°C<br>Derate above 25°C        | P <sub>D</sub>                    | 225<br>1.8  | mW<br>mW/°C |
| Thermal Resistance, Junction-to-Ambient   | $R_{\theta JA}$                   | 556         | °C/W        |
| Total Device Dissipation Alumina<br>Substrate (Note 2) T <sub>A</sub> = 25°C<br>Derate above 25°C | P <sub>D</sub>                    | 300<br>2.4  | mW<br>mW/°C |
| Thermal Resistance, Junction-to-Ambient   | $R_{\theta JA}$                   | 417         | °C/W        |
| Junction and Storage Temperature Range  | T <sub>J</sub> , T <sub>stg</sub> | -55 to +150 | °C          |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.
- 2. Alumina =  $0.4 \times 0.3 \times 0.024$  in. 99.5% alumina.
- 3. Reference SOA curve.





SOT-23 CASE 318 STYLE 6

#### **MARKING DIAGRAM**



xxx = 1P or M1B
M = Date Code\*
• = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25$ °C unless otherwise noted)

| Characteristic  |                | Symbol   | Min                  | Max   | Unit                         |                    |
|---|----------------|--|----------------------|---|------------------------------|--------------------|
| OFF CHARACTERISTICS   |                |  |                      |   |                              |                    |
| Collector – Emitter Breakdown Voltage (I <sub>C</sub> = 10 mAdo   | c, $I_B = 0$ ) | MMBT2222<br>MMBT2222A                                    | V <sub>(BR)CEO</sub> | 30<br>40                                      | _<br>_                       | Vdc                |
| Collector – Base Breakdown Voltage ( $I_C = 10 \mu Adc, I_I$  | E = 0)         | MMBT2222<br>MMBT2222A                                    | V <sub>(BR)CBO</sub> | 60<br>75                                      | -<br>-                       | Vdc                |
| Emitter – Base Breakdown Voltage ( $I_E = 10 \mu Adc, I_C$  | = 0)           | MMBT2222<br>MMBT2222A                                    | V <sub>(BR)EBO</sub> | 5.0<br>6.0                                    | -<br>-                       | Vdc                |
| Collector Cutoff Current<br>(V <sub>CE</sub> = 60 Vdc, V <sub>EB(off)</sub> = 3.0 Vdc)  | MMBT222        | 2A, SMMBT2222A   | I <sub>CEX</sub>     | -   | 10                           | nAdc               |
| Collector Cutoff Current ( $V_{CB} = 50 \text{ Vdc}$ , $I_{E} = 0$ )<br>( $V_{CB} = 60 \text{ Vdc}$ , $I_{E} = 0$ )<br>( $V_{CB} = 50 \text{ Vdc}$ , $I_{E} = 0$ , $T_{A} = 125^{\circ}\text{C}$ )<br>( $V_{CB} = 60 \text{ Vdc}$ , $I_{E} = 0$ , $T_{A} = 125^{\circ}\text{C}$ )   |                | MMBT2222<br>2A, SMMBT2222A<br>MMBT2222<br>2A, SMMBT2222A | І <sub>СВО</sub>     | -<br>-<br>-<br>-                              | 0.01<br>0.01<br>10<br>10     | μAdc               |
| Emitter Cutoff Current (V <sub>EB</sub> = 3.0 Vdc, I <sub>C</sub> = 0)  | MMBT222        | 2A, SMMBT2222A   | I <sub>EBO</sub>     | -   | 100                          | nAdc               |
| Base Cutoff Current (V <sub>CE</sub> = 60 Vdc, V <sub>EB(off)</sub> = 3.0 Vd  | lc) MMBT222    | 2A, SMMBT2222A   | I <sub>BL</sub>      | -   | 20                           | nAdc               |
| ON CHARACTERISTICS  |                |  |                      | •   |                              |                    |
| DC Current Gain $ \begin{array}{l} \text{(I}_C = 0.1 \text{ mAdc, } V_{CE} = 10 \text{ Vdc)} \\ \text{(I}_C = 1.0 \text{ mAdc, } V_{CE} = 10 \text{ Vdc)} \\ \text{(I}_C = 10 \text{ mAdc, } V_{CE} = 10 \text{ Vdc)} \\ \text{(I}_C = 10 \text{ mAdc, } V_{CE} = 10 \text{ Vdc)} \\ \text{(I}_C = 10 \text{ mAdc, } V_{CE} = 10 \text{ Vdc, } T_A = -55^{\circ}\text{C)} \\ \text{(I}_C = 150 \text{ mAdc, } V_{CE} = 10 \text{ Vdc)} \text{ (Note 4)} \\ \text{(I}_C = 150 \text{ mAdc, } V_{CE} = 1.0 \text{ Vdc)} \text{ (Note 4)} \\ \text{(I}_C = 500 \text{ mAdc, } V_{CE} = 10 \text{ Vdc)} \text{ (Note 4)} \\ \end{array} $ | MMBT2222       | MMBT2222A only<br>MMBT2222<br>2A, SMMBT2222A             | h <sub>FE</sub>      | 35<br>50<br>75<br>35<br>100<br>50<br>30<br>40 | -<br>-<br>-<br>300<br>-<br>- | -                  |
| Collector – Emitter Saturation Voltage (Note 4)<br>(I <sub>C</sub> = 150 mAdc, I <sub>B</sub> = 15 mAdc)  | MMBT222        | MMBT2222<br>2A, SMMBT2222A                               | V <sub>CE(sat)</sub> | -<br>-  | 0.4<br>0.3                   | Vdc                |
| $(I_C = 500 \text{ mAdc}, I_B = 50 \text{ mAdc})$   | MMBT222        | MMBT2222<br>2A, SMMBT2222A                               |                      | -<br>-  | 1.6<br>1.0                   |                    |
| Base – Emitter Saturation Voltage (Note 4)<br>(I <sub>C</sub> = 150 mAdc, I <sub>B</sub> = 15 mAdc)   | MMBT222        | MMBT2222<br>2A, SMMBT2222A                               | V <sub>BE(sat)</sub> | _<br>0.6                                      | 1.3<br>1.2                   | Vdc                |
| $(I_C = 500 \text{ mAdc}, I_B = 50 \text{ mAdc})$   | MMBT222        | MMBT2222<br>2A, SMMBT2222A                               |                      | -<br>-  | 2.6<br>2.0                   |                    |
| SMALL-SIGNAL CHARACTERISTICS  |                |  |                      | •   | •                            |                    |
| Current-Gain - Bandwidth Product (Note 5)<br>(I <sub>C</sub> = 20 mAdc, V <sub>CE</sub> = 20 Vdc, f = 100 MHz)  | MMBT222        | MMBT2222<br>2A, SMMBT2222A                               | f <sub>T</sub>       | 250<br>300                                    | _<br>_                       | MHz                |
| Output Capacitance<br>(V <sub>CB</sub> = 10 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)   |                |  | C <sub>obo</sub>     | -   | 8.0                          | pF                 |
| Input Capacitance ( $V_{EB} = 0.5 \text{ Vdc}$ , $I_{C} = 0$ , $f = 1.0 \text{ MHz}$ )  | MMBT222        | MMBT2222<br>2A, SMMBT2222A                               | C <sub>ibo</sub>     | -<br>-  | 30<br>25                     | pF                 |
| Input Impedance (I <sub>C</sub> = 1.0 mAdc, $V_{CE}$ = 10 Vdc, f = 1.0 kHz) (I <sub>C</sub> = 10 mAdc, $V_{CE}$ = 10 Vdc, f = 1.0 kHz)  |                | 2A, SMMBT2222A<br>2A, SMMBT2222A                         | h <sub>ie</sub>      | 2.0<br>0.25                                   | 8.0<br>1.25                  | kΩ                 |
| Voltage Feedback Ratio<br>( $I_C = 1.0 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ )<br>( $I_C = 10 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ )   |                | 2A, SMMBT2222A<br>2A, SMMBT2222A                         | h <sub>re</sub>      | -<br>-  | 8.0<br>4.0                   | X 10 <sup>-4</sup> |
| Small – Signal Current Gain<br>( $I_C = 1.0$ mAdc, $V_{CE} = 10$ Vdc, $f = 1.0$ kHz)<br>( $I_C = 10$ mAdc, $V_{CE} = 10$ Vdc, $f = 1.0$ kHz)  |                | 2A, SMMBT2222A<br>2A, SMMBT2222A                         | h <sub>fe</sub>      | 50<br>75                                      | 300<br>375                   | -                  |

#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

| Charact   | Symbol   | Min                | Max       | Unit      |       |
|---|--|--------------------|-----------|-----------|-------|
| SMALL-SIGNAL CHARACTERISTICS  |  |                    | •         |           |       |
| Output Admittance ( $I_C = 1.0 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ kH}$ ( $I_C = 10 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ |  | h <sub>oe</sub>    | 5.0<br>25 | 35<br>200 | μmhos |
| Collector Base Time Constant (I <sub>E</sub> = 20 mAdc, V <sub>CB</sub> = 20 Vdc, f = 31.8 MHz) MMBT2222A, SMMBT2222A   |  | rb, C <sub>c</sub> | -         | 150       | ps    |
| Noise Figure (I <sub>C</sub> = 100 $\mu$ Adc, V <sub>CE</sub> = 10 Vdc, R <sub>S</sub> = 1.0 k $\Omega$ , f = 1.0 kHz) MMBT2222A, SMMBT2222A                                  |  |                    | -         | 4.0       | dB    |
| SWITCHING CHARACTERISTICS (MMBT2  | 222A only)   |                    | •         |           | •     |
| Delay Time  | $(V_{CC} = 30 \text{ Vdc}, V_{BE(off)} = -0.5 \text{ Vdc},$  | t <sub>d</sub>     | _         | 10        |       |
| Rise Time   | $(V_{CC} = 30 \text{ Vdc}, V_{BE(off)} = -0.5 \text{ Vdc}, \\ I_{C} = 150 \text{ mAdc}, I_{B1} = 15 \text{ mAdc})$ | t <sub>r</sub>     | _         | 25        | ns    |
| Storage Time  | (V <sub>CC</sub> = 30 Vdc, I <sub>C</sub> = 150 mAdc,  | t <sub>s</sub>     | -         | 225       |       |
| Fall Time   | $I_{B1} = I_{B2} = 15 \text{ mAdc}$  | t <sub>f</sub>     | _         | 60        | ns    |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- 4. Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%.
- 5. f<sub>T</sub> is defined as the frequency at which |h<sub>fe</sub>| extrapolates to unity.

#### **SWITCHING TIME EQUIVALENT TEST CIRCUITS**

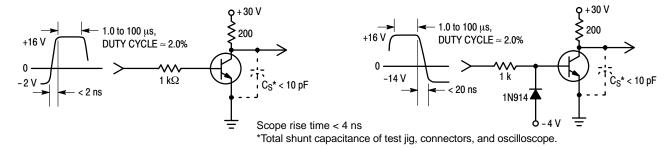


Figure 1. Turn-On Time

Figure 2. Turn-Off Time

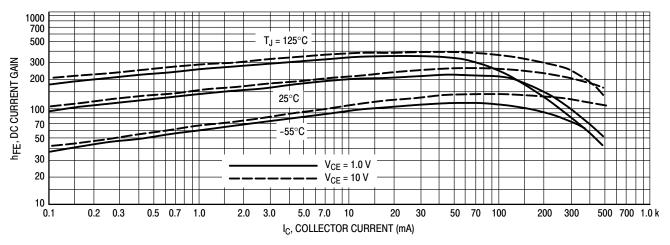


Figure 3. DC Current Gain

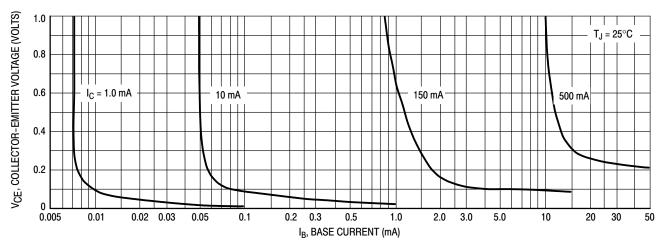


Figure 4. Collector Saturation Region

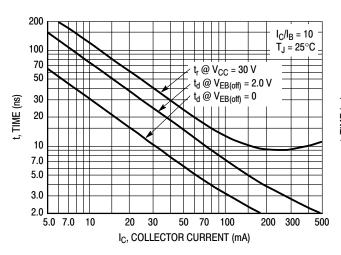


Figure 5. Turn-On Time

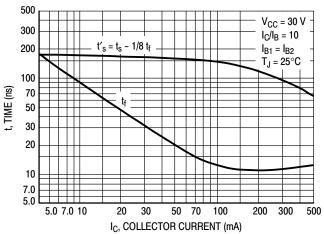


Figure 6. Turn-Off Time

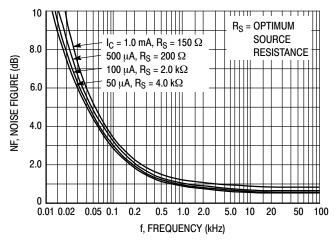


Figure 7. Frequency Effects

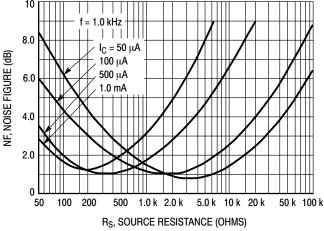
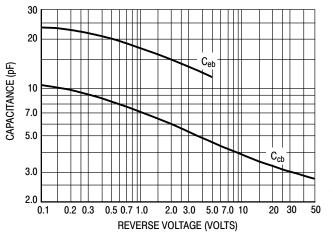


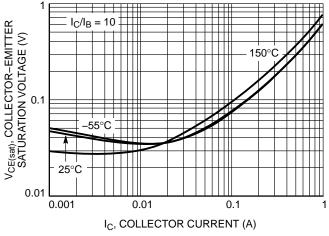
Figure 8. Source Resistance Effects



f<sub>T</sub>, CURRENT-GAIN BANDWIDTH PRODUCT (MHz) 500 V<sub>CE</sub> = 20 V  $T_J = 25^{\circ}C$ 300 200 100 70 50 70 100 1.0 2.0 3.0 5.0 7.0 20 50 IC, COLLECTOR CURRENT (mA)

Figure 9. Capacitances

Figure 10. Current-Gain Bandwidth Product



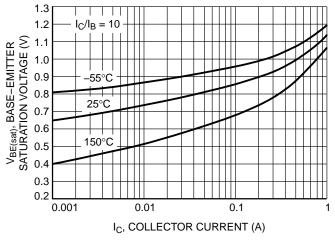
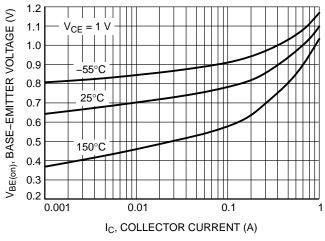


Figure 11. Collector Emitter Saturation Voltage vs. Collector Current

Figure 12. Base Emitter Saturation Voltage vs.
Collector Current



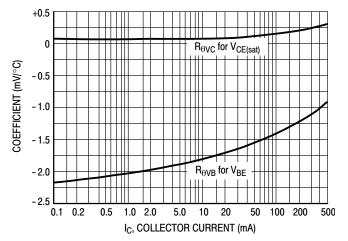


Figure 13. Base Emitter Voltage vs. Collector Current

**Figure 14. Temperature Coefficients** 

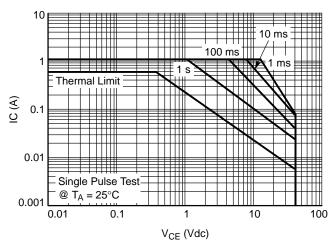


Figure 15. Safe Operating Area

#### **ORDERING INFORMATION**

| Device                           | Specific Marking Code | Package             | Shipping <sup>†</sup> |
|----------------------------------|-----------------------|---------------------|-----------------------|
| MMBT2222LT1G                     | M1B                   | SOT-23<br>(Pb-Free) | 3000 / Tape & Reel    |
| MMBT2222ALT1G,<br>SMMBT2222ALT1G | 1P                    | SOT-23<br>(Pb-Free) | 3000 / Tape & Reel    |
| MMBT2222LT3G                     | M1B                   | SOT-23<br>(Pb-Free) | 10,000 / Tape & Reel  |
| MMBT2222ALT3G,<br>SMMBT2222ALT3G | 1P                    | SOT-23<br>(Pb-Free) | 10,000 / Tape & Reel  |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>\*</sup>S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

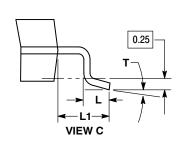


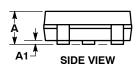
SOT-23 (TO-236) CASE 318-08 **ISSUE AS** 

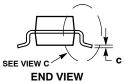
**DATE 30 JAN 2018** 

## SCALE 4:1 D - 3X b

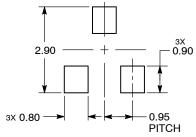
**TOP VIEW** 







#### **RECOMMENDED SOLDERING FOOTPRINT**



DIMENSIONS: MILLIMETERS

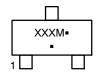
3. ANODE

#### NOTES:

- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH.
  MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

|     | MILLIMETERS |      |      |       | INCHES |       |
|-----|-------------|------|------|-------|--------|-------|
| DIM | MIN         | NOM  | MAX  | MIN   | NOM    | MAX   |
| Α   | 0.89        | 1.00 | 1.11 | 0.035 | 0.039  | 0.044 |
| A1  | 0.01        | 0.06 | 0.10 | 0.000 | 0.002  | 0.004 |
| b   | 0.37        | 0.44 | 0.50 | 0.015 | 0.017  | 0.020 |
| С   | 0.08        | 0.14 | 0.20 | 0.003 | 0.006  | 0.008 |
| D   | 2.80        | 2.90 | 3.04 | 0.110 | 0.114  | 0.120 |
| E   | 1.20        | 1.30 | 1.40 | 0.047 | 0.051  | 0.055 |
| е   | 1.78        | 1.90 | 2.04 | 0.070 | 0.075  | 0.080 |
| L   | 0.30        | 0.43 | 0.55 | 0.012 | 0.017  | 0.022 |
| L1  | 0.35        | 0.54 | 0.69 | 0.014 | 0.021  | 0.027 |
| HE  | 2.10        | 2.40 | 2.64 | 0.083 | 0.094  | 0.104 |
| Т   | O٥          |      | 100  | O٥    |        | 10°   |

#### **GENERIC MARKING DIAGRAM\***



XXX = Specific Device Code

= Date Code

= Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

| STYLE 1 THRU 5:<br>CANCELLED              | STYLE 6:<br>PIN 1. BASE<br>2. EMITTER<br>3. COLLECTOR | STYLE 7:<br>PIN 1. EMITTER<br>2. BASE<br>3. COLLECTOR | STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE |                  |                  |
|---|---|---|---|------------------|------------------|
| STYLE 9:                                  | STYLE 10:   | STYLE 11:   | STYLE 12:   | STYLE 13:        | STYLE 14:        |
| PIN 1. ANODE                              | PIN 1. DRAIN  | PIN 1. ANODE  | PIN 1. CATHODE                                    | PIN 1. SOURCE    | PIN 1. CATHODE   |
| 2. ANODE                                  | 2. SOURCE   | 2. CATHODE  | 2. CATHODE  | 2. DRAIN         | 2. GATE          |
| 3. CATHODE                                | 3. GATE   | 3. CATHODE-ANODE                                      | 3. ANODE  | 3. GATE          | 3. ANODE         |
| STYLE 15:                                 | STYLE 16:   | STYLE 17:   | STYLE 18:   | STYLE 19:        | STYLE 20:        |
| PIN 1. GATE                               | PIN 1. ANODE  | PIN 1. NO CONNECTION                                  | PIN 1. NO CONNECTION                              | PIN 1. CATHODE   | PIN 1. CATHODE   |
| 2. CATHODE                                | 2. CATHODE  | 2. ANODE  | 2. CATHODE  | 2. ANODE         | 2. ANODE         |
| 3. ANODE                                  | 3. CATHODE  | 3. CATHODE  | 3. ANODE  | 3. CATHODE-ANODE | 3. GATE          |
| STYLE 21:                                 | STYLE 22:   | STYLE 23:   | STYLE 24:   | STYLE 25:        | STYLE 26:        |
| PIN 1. GATE                               | PIN 1. RETURN   | PIN 1. ANODE  | PIN 1. GATE                                       | PIN 1. ANODE     | PIN 1. CATHODE   |
| 2. SOURCE                                 | 2. OUTPUT   | 2. ANODE  | 2. DRAIN  | 2. CATHODE       | 2. ANODE         |
| 3. DRAIN                                  | 3. INPUT  | 3. CATHODE  | 3. SOURCE   | 3. GATE          | 3. NO CONNECTION |
| STYLE 27:<br>PIN 1. CATHODE<br>2. CATHODE | STYLE 28:<br>PIN 1. ANODE<br>2. ANODE                 |   |   |                  |                  |

| DOCUMENT NUMBER: | 98ASB42226B     | Electronic versions are uncontrolled except when accessed directly from the Document Reposi<br>Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |             |  |
|------------------|-----------------|--|-------------|--|
| DESCRIPTION:     | SOT-23 (TO-236) |  | PAGE 1 OF 1 |  |

ON Semiconductor and (III) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

3. CATHODE

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <a href="www.onsemi.com/site/pdf/Patent-Marking.pdf">www.onsemi.com/site/pdf/Patent-Marking.pdf</a>. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any EDA class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer pu

#### **PUBLICATION ORDERING INFORMATION**

LITERATURE FULFILLMENT:
Email Requests to: orderlit@onsemi.com

onsemi Website: www.onsemi.com

TECHNICAL SUPPORT North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative

## **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Bipolar Transistors - BJT category:

Click to view products by ON Semiconductor manufacturer:

Other Similar products are found below:

619691C MCH4017-TL-H BC546/116 BC557/116 BSW67A NTE158 NTE187A NTE195A NTE2302 NTE2330 NTE63 C4460

2SA1419T-TD-H 2SA1721-O(TE85L,F) 2SA2126-E 2SB1204S-TL-E 2SC5488A-TL-H 2SD2150T100R SP000011176 FMMTA92QTA

2N2369ADCSM 2SC2412KT146S 2SC5490A-TL-H 2SD1816S-TL-E 2SD1816T-TL-E CMXT2207 TR CPH6501-TL-E MCH4021-TL-E

US6T6TR 732314D CMXT3906 TR CPH3121-TL-E CPH6021-TL-H 873787E UMX21NTR EMT2T2R MCH6102-TL-E FP204-TL-E

NJL0302DG 2N3583 2SA1434-TB-E 2SC3143-4-TB-E 2SD1621S-TD-E NTE103 30A02MH-TL-E NSV40301MZ4T1G NTE101 NTE13

NTE15 NTE16001